



EPO-TEK® H20E-LV

Technical Data Sheet
For Reference Only

Electrically Conductive, Silver Epoxy

Date: September 2017
Rev: III
No. of Components: Two
Mix Ratio by Weight: 1 : 1
Specific Gravity: Part A: 1.93 Part B: 3.07
Pot Life: 3 Days
Shelf Life- Bulk: One year at room temperature

Recommended Cure: 150°C / 1 Hour

Minimum Alternative Cure(s):

May not achieve performance properties listed below

175°C / 45 Seconds

150°C / 5 Minutes

120°C / 15 Minutes

80°C / 3 Hours

NOTES:

- Container(s) should be kept closed when not in use.
- Filled systems should be stirred thoroughly before mixing and prior to use.
- Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

Product Description: EPO-TEK® H20E-LV is a two component, 100% solids silver-filled epoxy system designed specifically for chip bonding in microelectronic and optoelectronic applications. It is a low viscosity version of EPO-TEK® H20E, semiconductor die-attach epoxy.

Typical Properties: Cure condition: 150°C / 1 Hour Different batches, conditions & applications yield differing results.

Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:

* Color (before cure):	Part A: Silver	Part B: Silver
* Consistency:	Smooth flowing paste	
* Viscosity (23°C) @ 100 rpm:	1,800 - 2,800	cPs
Thixotropic Index:	3.4	
* Glass Transition Temp:	≥ 80	°C (Dynamic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min)
Coefficient of Thermal Expansion (CTE):	Below Tg:	26 x 10 ⁻⁶ in/in°C
	Above Tg:	93 x 10 ⁻⁶ in/in°C
Shore D Hardness:	86	
Lap Shear @ 23°C:	1,500	psi
Die Shear @ 23°C:	≥ 5	Kg 1,778 psi
Degradation Temp:	400	°C
Weight Loss:		
	@ 300°C:	2.34 %
Suggested Operating Temperature:	< 300	°C (Intermittent)
Storage Modulus:	640,479	psi
Ion Content:	Cl ⁻ :	102 ppm
	Na ⁺ :	98 ppm
	NH ₄ ⁺ :	320 ppm
	K ⁺ :	25 ppm
* Particle Size:	≤ 45	microns

ELECTRICAL AND THERMAL PROPERTIES:

Thermal Conductivity:	2.5	W/mK
* Volume Resistivity @ 23°C:	≤ 0.0004	Ohm-cm

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This information is based on data and tests believed to be accurate. Epoxy Technology, Inc. makes no warranties (expressed or implied) as to its accuracy and assumes no liability in connection with any use of this product.

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EPO-TEK® H20E-LV Advantages & Suggested Application Notes:

- Especially recommended for use in high speed epoxy chip bonding systems where very fast cures are desired.
- Suggested for JEDEC Level III and II for plastic IC packaging.
- Capable of resisting TC wire bonding temperatures in the range of 300°C to 400°C.
- Ease of use: apply by dispensing, screen printing, die-stamping, or by hand.
- Especially suited for high power devices and high current flow; high power LEDs.
- Opto-electronic packaging material: LED, LCDs, and fiber optic components.

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